## MSA-0505

# Cascadable Silicon Bipolar MMIC Amplifier



# **Data Sheet**

### Description

The MSA-0505 is a high performance medium power silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount package. This MMIC is designed for use as a general purpose  $50\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial systems.

The MSA-series is fabricated using Avago's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

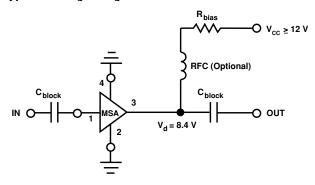
#### **Features**

- Cascadable 50 Ω Gain Block
- High Output Power:
   18.0 dBm Typical P<sub>1 dB</sub> at 1.0 GHz
- Low Distortion:
   29.0 dBm Typical IP<sub>3</sub> at 1.0 GHz
- 7.0 dB Typical Gain at 1.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

#### **05 Plastic Package**



#### **Typical Biasing Configuration**



## MSA-0505 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>				
Device Current	135 mA				
Power Dissipation <sup>[2,3]</sup>	1.5 W				
RF Input Power	+25 dBm				
Junction Temperature	200°C				
Storage Temperature	−65 to 150°C				

## Thermal Resistance<sup>[2]</sup>:

 $\theta_{ic} = 85^{\circ}\text{C/W}$ 

#### Notes:

- 1. Permanent damage may occur if any of these limits are exceeded.
- T<sub>CASE</sub> = 25°C.
   Derate at 11.8 mW/°C for T<sub>C</sub> > 73°C.

# Electrical Specifications<sup>[1]</sup>, $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions: $I_d = 80 \text{ m}$	Units	Min.	Тур.	Max.	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 0.5 GHz f = 1.0 GHz	dBm dBm	16.0	19.0 18.0	
G <sub>P</sub>	Power Gain ( S <sub>21</sub>   <sup>2</sup> )	f = 0.5 GHz f = 1.0 GHz	dB	6.0	7.5 7.0	
$\DeltaG_P$	Gain Flatness	f = 0.1 to 1.5 GHz	dB		±0.75	
f <sub>3 dB</sub>	3 dB Bandwidth <sup>[2]</sup>		GHz		2.3	
VCMD	Input VSWR	f = 0.1 to 1.5 GHz			1.6:1	
VSWR —	Output VSWR	f = 0.1 to 1.5 GHz			2.0:1	
IP <sub>3</sub>	Third Order Intercept Point	f = 1.0 GHz	dBm		29.0	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		6.5	
t <sub>D</sub>	Group Delay	f = 1.0 GHz	psec		190	
V <sub>d</sub>	Device Voltage		V	6.7	8.4	10.1
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-16.0	

## **Ordering Information**

Part Numbers	No. of Devices	Comments
MSA-0505-STR	10	Bulk
MSA-0505-STRG	100	Bulk
MSA-0505-TR1	500	7" Reel
MSA-0505-TR1G	500	7" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

<sup>1.</sup> The recommended operating current range for this device is 60 to 100 mA. Typical performance as a function of current is on the following page.

2. Referenced from 0.1 GHz Gain (GP).

# MSA-0505 Typical Scattering Parameters (T\_A = 25 °C, I\_d = 80 mA)

Freq.	S <sub>11</sub>		S <sub>21</sub>			<b>S</b> <sub>1</sub>			S <sub>22</sub>		
MHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
5	.56	-39	14.9	5.56	161	-18.5	.120	39	.65	-36	0.60
25	.24	-103	9.7	3.05	156	-13.9	.202	12	.25	-90	0.97
50	.15	-130	8.2	2.57	163	-13.7	.207	7	.15	-116	1.15
100	.13	-155	7.8	2.45	165	-13.7	.207	3	.11	-132	1.21
200	.12	-170	7.7	3.43	161	-13.5	.211	1	.11	-145	1.21
400	.12	178	7.5	2.37	148	-13.6	.209	-1	.14	-146	1.23
600	.13	172	7.4	2.34	134	-13.6	.209	-2	.17	-151	1.23
800	.13	168	7.2	2.29	119	-13.6	.209	-3	.21	-157	1.23
1000	.14	166	7.0	2.24	105	-13.4	.213	-4	.25	-164	1.21
1500	.21	159	6.4	2.09	72	-13.3	.217	-6	.34	176	1.16
2000	.30	148	5.2	1.82	42	-13.1	.222	<b>-9</b>	.42	159	1.12
2500	.40	136	4.1	1.60	17	-12.9	.227	-11	.48	146	1.05
3000	.52	121	2.7	1.36	-7	-12.6	.234	-16	.55	133	0.92

# Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

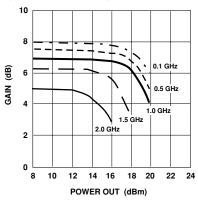


Figure 1. Typical Gain vs. Power Out,  $T_A = 25^{\circ}$ C,  $I_d = 80$  mA.

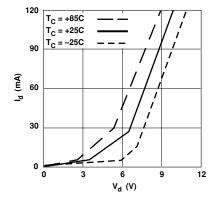


Figure 2. Device Current vs. Voltage.

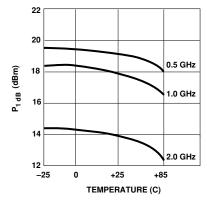


Figure 3. Output Power at 1 dB Gain Compression, vs. Case Temperature,  $\rm I_{\rm d}=80~mA.$ 

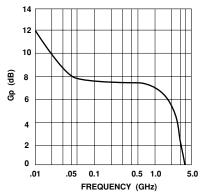


Figure 4. Gain vs. Frequency,  $I_d = 80$  to 100 mA.

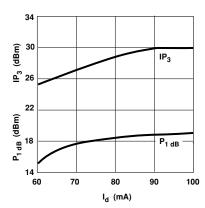
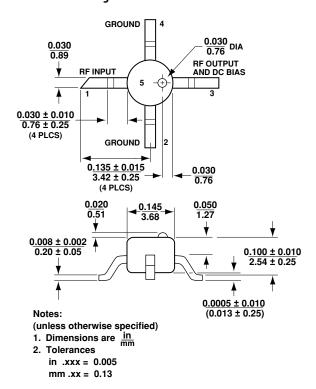


Figure 5. Output Power at 1 dB Gain Compression, Third Order Intercept vs. Case Temperature,  $f=1.0\ GHz.$ 

## **05 Plastic Package Dimensions**



For product information and a complete list of distributors, please go to our web site:

www.avagotech.com

